NSN 5961-01-339-7333

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-7333 **Inclosure Material:** Ceramic or metal **Overall Length:** Between 0.205 inches and 0.225 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **Mounting Method:** Press fit **Features Provided:** Burn in and quality assurance level txv **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

Fiig: A110a0